

10V Drive Nch MOSFET

R6046ANZ

● Structure

Silicon N-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) Low input capacitance.
- 3) High ESD.

● Application

Switching

● Packaging specifications

Type	Package	Bulk
	Code	-
	Basic ordering unit (pieces)	360
R6046ANZ		○

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DS}	600	V
Gate-source voltage		V_{GS}	±30	V
Drain current	Continuous	I_D *3	±46	A
	Pulsed	I_{DP} *1	±115	A
Source current (Body Diode)	Continuous	I_S *3	46	A
	Pulsed	I_{SP} *1	115	A
Avalanche current		I_{AS} *2	23	A
Avalanche energy		E_{AS} *2	142	mJ
Power dissipation		P_D *4	120	W
Channel temperature		T_{ch}	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

 *1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

 *2 $L = 500 \mu H$, $V_{DD} = 50V$, $R_G = 25 \Omega$, $T_{ch} = 25^\circ C$

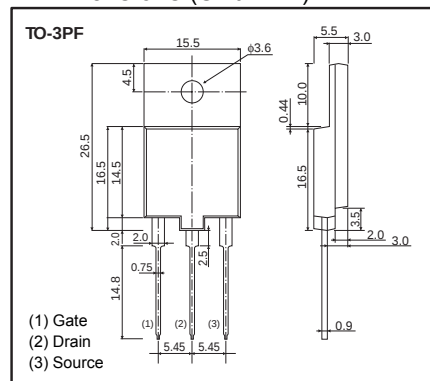
*3 Limited only by maximum channel temperature allowed.

 *4 $T_C = 25^\circ C$

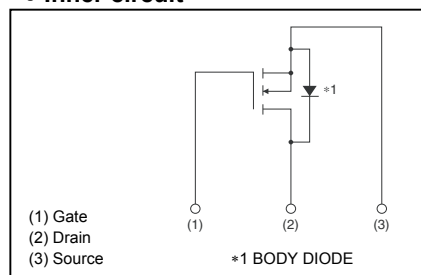
● Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to Case	$R_{th(ch-c)}$	1.04	°C / W

● Dimensions (Unit : mm)



● Inner circuit



● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	± 100	nA	$V_{GS} = \pm 30V$, $V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	600	-	-	V	$I_D = 1mA$, $V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	-	-	100	μA	$V_{DS} = 600V$, $V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	2.5	-	4.5	V	$V_{DS} = 10V$, $I_D = 1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	65	81	m Ω	$I_D = 23A$, $V_{GS} = 10V$
Forward transfer admittance	$ Y_{fs} ^*$	19	33	-	S	$V_{DS} = 10V$, $I_D = 23A$
Input capacitance	C_{iss}	-	6000	-	pF	$V_{DS} = 25V$
Output capacitance	C_{oss}	-	3900	-	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	-	90	-	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	60	-	ns	$V_{DD} = 300V$, $I_D = 23A$
Rise time	t_r^*	-	130	-	ns	$V_{GS} = 10V$
Turn-off delay time	$t_{d(off)}^*$	-	230	-	ns	$R_L = 13.0\Omega$
Fall time	t_f^*	-	100	-	ns	$R_G = 10\Omega$
Total gate charge	Q_g^*	-	150	-	nC	$V_{DD} = 300V$
Gate-source charge	Q_{gs}^*	-	35	-	nC	$I_D = 46A$
Gate-drain charge	Q_{gd}^*	-	55	-	nC	$V_{GS} = 10V$

*Pulsed

● Body diode characteristics (Source-Drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_{SD}^*	-	-	1.5	V	$I_S = 46A$, $V_{GS} = 0V$

*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics (I)

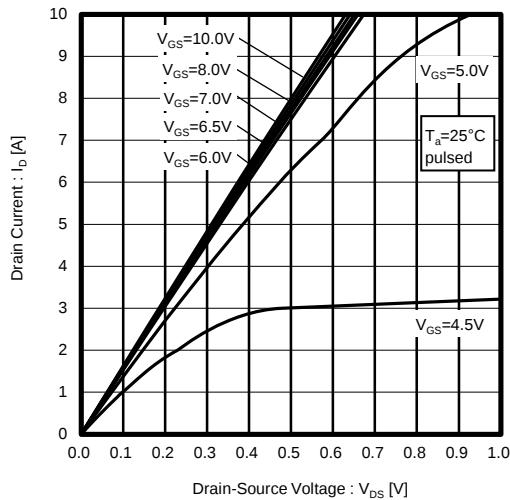


Fig.2 Typical Output Characteristics (II)

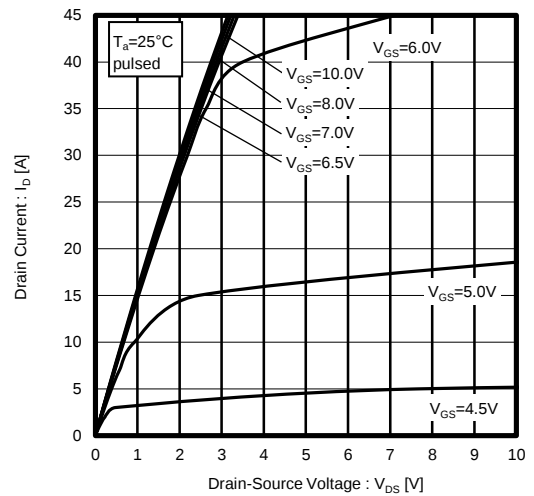


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

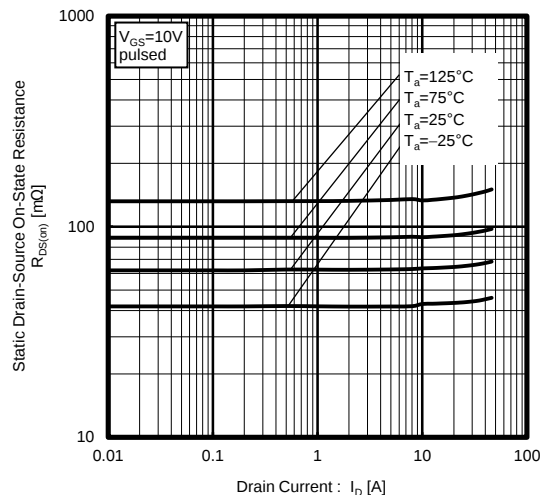


Fig.4 Static Drain-Source On-State Resistance vs. Channel Temperature

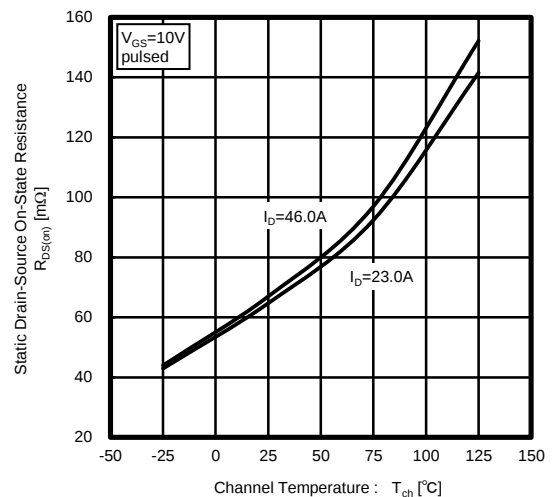


Fig.5 Typical Transfer Characteristics

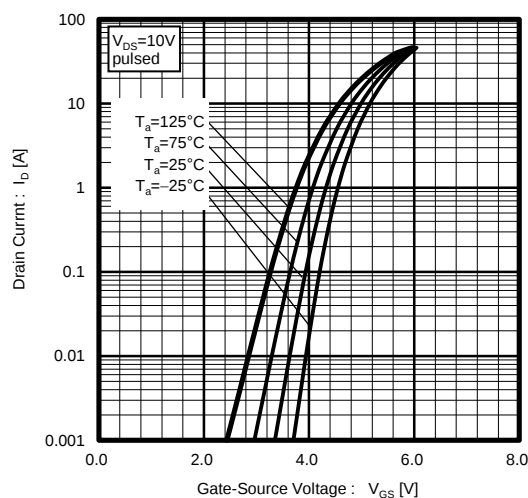


Fig.6 Gate Threshold Voltage vs. Channel Temperature

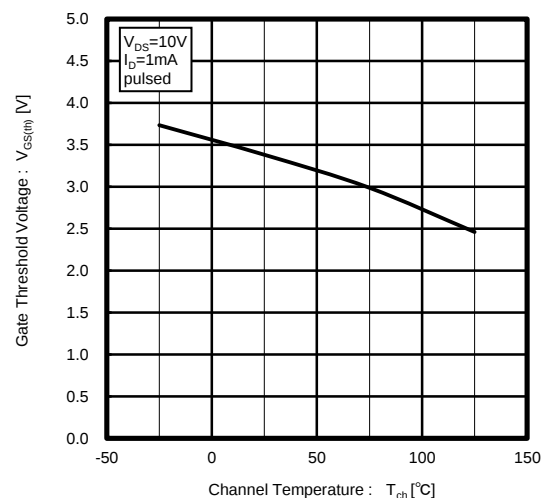


Fig.7 Forward Transfer Admittance vs. Drain Current

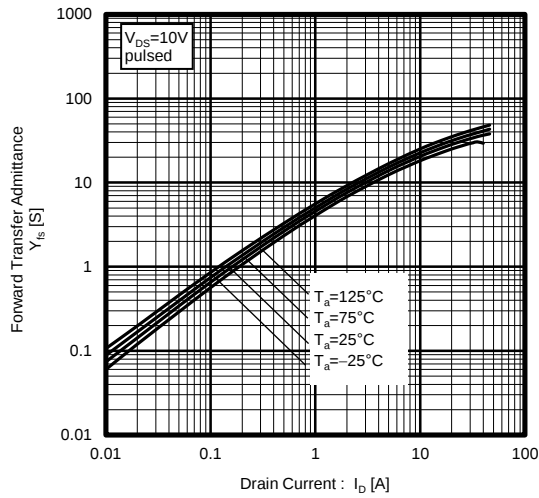


Fig.8 Source Current vs. Source-Drain Voltage

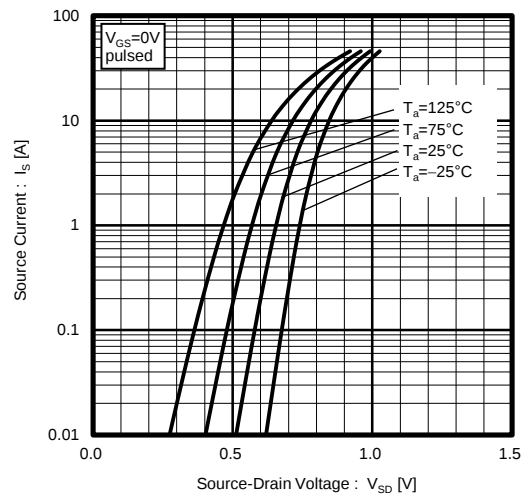


Fig.9 Switching Characteristics

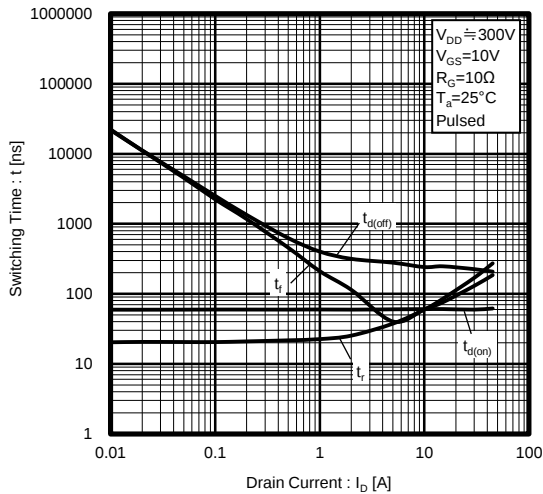


Fig.10 Dynamic Input Characteristics

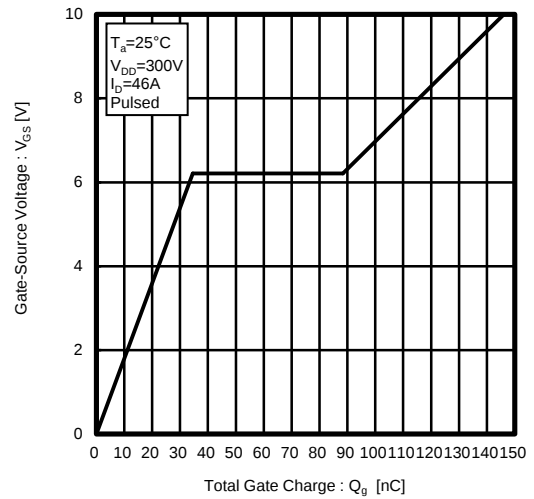


Fig.11 Typical Capacitance vs. Drain-Source Voltage

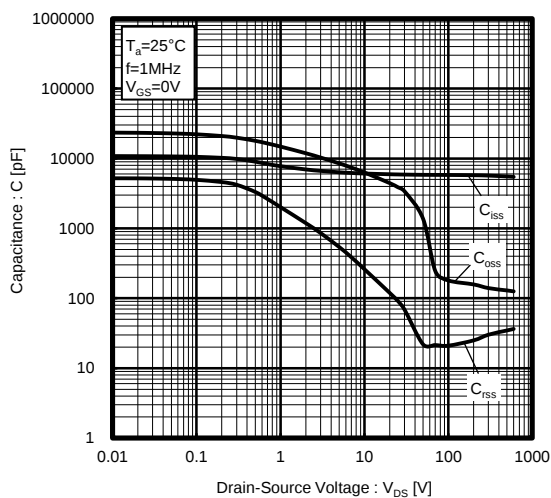
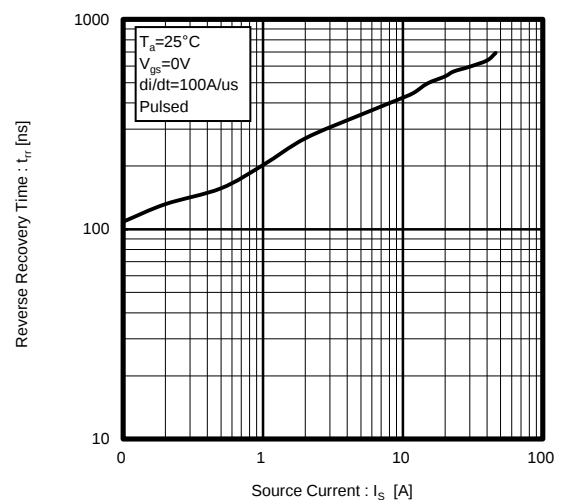


Fig.12 Reverse Recovery Time vs. Source Current



● Measurement circuits

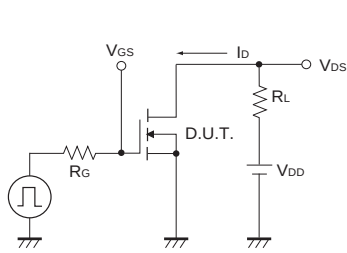


Fig.1-1 Switching Time Measurement Circuit

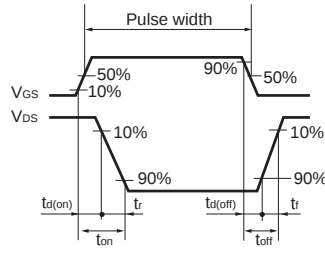


Fig.1-2 Switching Waveforms

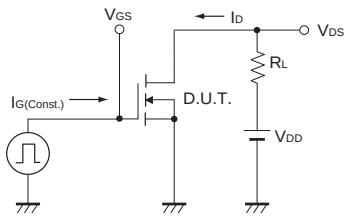


Fig.2-1 Gate Charge Measurement Circuit

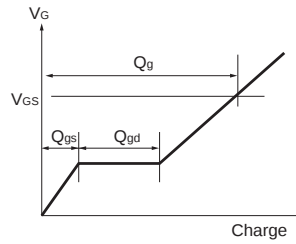


Fig.2-2 Gate Charge Waveform

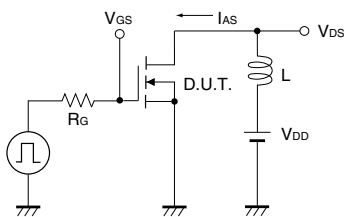


Fig.3-1 Avalanche Measurement Circuit

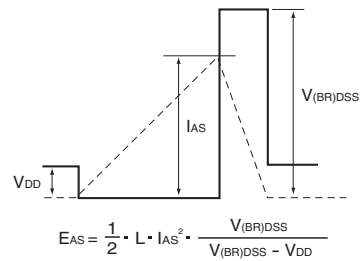


Fig.3-2 Avalanche Waveform

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